

NCP115

LDO Regulator - High PSRR

300 mA

The NCP115 is 300 mA LDO that provides the engineer with a very stable, accurate voltage with low noise suitable for space constrained, noise sensitive applications. In order to optimize performance for battery operated portable applications, the NCP115 employs the dynamic quiescent current adjustment for very low I_Q consumption at no-load.

Features

- Operating Input Voltage Range: 1.7 V to 5.5 V
- Available in Fixed Voltage Options: 0.8 V to 3.6 V Contact Factory for Other Voltage Options
- Very Low Quiescent Current of Typ. 50 μ A
- Soft Start Feature with Two V_{OUT} Slew Rate Speed
- Standby Current Consumption: Typ. 0.1 μ A
- Low Dropout: 250 mV Typical at 300 mA @ 2.8 V
- $\pm 1\%$ Accuracy at Room Temperature
- High Power Supply Ripple Rejection: 70 dB at 1 kHz
- Thermal Shutdown and Current Limit Protections
- Available in XDFN4 and TSOP-5 Packages
- Stable with a 1 μ F Ceramic Output Capacitor
- These are Pb-Free Devices

Typical Applications

- PDAs, Mobile phones, GPS, Smartphones
- Wireless Handsets, Wireless LAN, Bluetooth[®], Zigbee[®]
- Portable Medical Equipment
- Other Battery Powered Applications

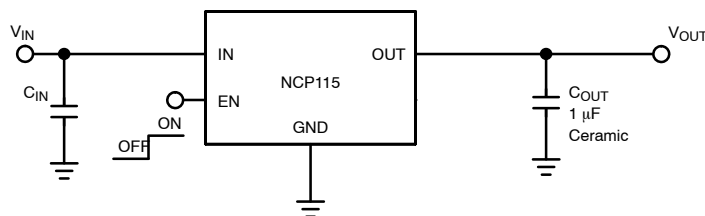


Figure 1. Typical Application Schematic



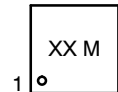
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MARKING DIAGRAMS



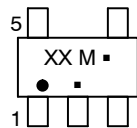
XDFN4
CASE 711AJ



XX = Specific Device Code
M = Date Code



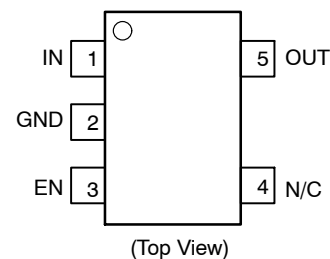
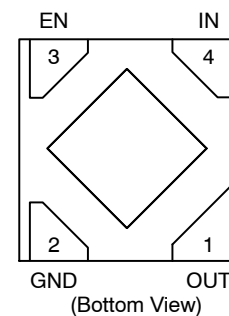
TSOP-5
CASE 483



XX = Device Code
M = Date Code*
■ = Pb-Free Package

(Note: Microdot may be in either location)
*Date Code orientation and/or position may vary depending upon manufacturing location.

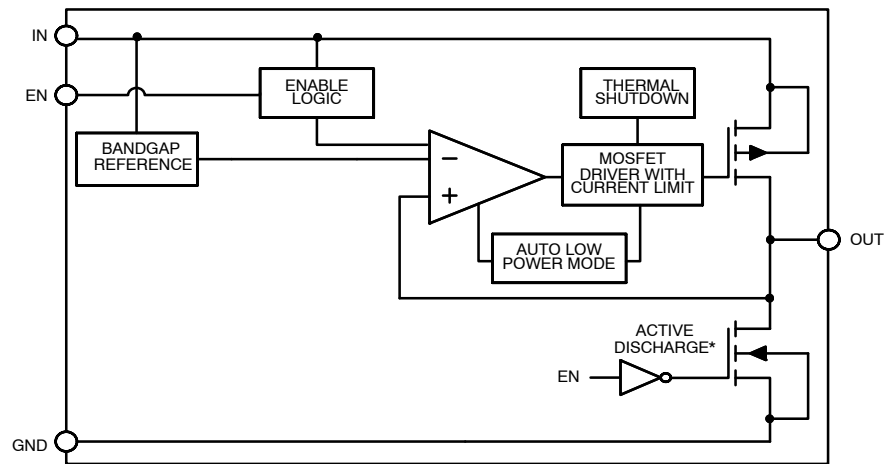
PIN CONNECTIONS



ORDERING INFORMATION

See detailed ordering, marking and shipping information on page 15 of this data sheet.

NCP115



*Active output discharge function is present only in NCP115A and NCP115C devices.
yyy denotes the particular V_{OUT} option.

Figure 2. Simplified Schematic Block Diagram

PIN FUNCTION DESCRIPTION

Pin No. (XDFN4)	Pin No. (TSOP5)	Pin Name	Description
1	5	OUT	Regulated output voltage pin. A small ceramic capacitor with minimum value of 1 μ F is needed from this pin to ground to assure stability.
2	2	GND	Power supply ground.
3	3	EN	Driving EN over 0.9 V turns on the regulator. Driving EN below 0.4 V puts the regulator into shutdown mode.
4	1	IN	Input pin. A small capacitor is needed from this pin to ground to assure stability.
-	4	N/C	Not connected. This pin can be tied to ground to improve thermal dissipation.
-	-	EPAD	Exposed pad should be connected directly to the GND pin. Soldered to a large ground copper plane allows for effective heat removal.

ABSOLUTE MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Input Voltage (Note 1)	V_{IN}	-0.3 V to 6 V	V
Output Voltage	V_{OUT}	-0.3 V to $V_{IN} + 0.3$ V or 6 V	V
Enable Input	V_{EN}	-0.3 V to 6 V	V
Output Short Circuit Duration	t_{SC}	∞	s
Maximum Junction Temperature	$T_{J(MAX)}$	150	$^{\circ}$ C
Storage Temperature	T_{STG}	-55 to 150	$^{\circ}$ C
ESD Capability, Human Body Model (Note 2)	ESD_{HBM}	2000	V
ESD Capability, Machine Model (Note 2)	ESD_{MM}	200	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- Refer to ELECTRICAL CHARACTERISTICS and APPLICATION INFORMATION for Safe Operating Area.
- This device series incorporates ESD protection and is tested by the following methods:
ESD Human Body Model tested per EIA/JESD22-A114,
ESD Machine Model tested per EIA/JESD22-A115,
Latchup Current Maximum Rating tested per JEDEC standard: JESD78.

THERMAL CHARACTERISTICS (Note 3)

Rating	Symbol	Value	Unit
Thermal Characteristics, XDFN4 1x1 mm Thermal Resistance, Junction-to-Air	$R_{\theta JA}$	208	$^{\circ}$ C/W
Thermal Characteristics, TSOP-5 Thermal Resistance, Junction-to-Air	$R_{\theta JA}$	162	$^{\circ}$ C/W

- Single component mounted on 1 oz, FR 4 PCB with 645 mm² Cu area.

NCP115

ELECTRICAL CHARACTERISTICS $-40^{\circ}\text{C} \leq T_J \leq 85^{\circ}\text{C}$; $V_{IN} = V_{OUT(NOM)} + 1\text{ V}$ for V_{OUT} options greater than 1.5 V. Otherwise $V_{IN} = 2.5\text{ V}$, whichever is greater; $I_{OUT} = 1\text{ mA}$, $C_{IN} = C_{OUT} = 1\text{ }\mu\text{F}$, unless otherwise noted. $V_{EN} = 0.9\text{ V}$. Typical values are at $T_J = +25^{\circ}\text{C}$. Min./Max. are for $T_J = -40^{\circ}\text{C}$ and $T_J = +85^{\circ}\text{C}$ respectively (Note 4).

Parameter	Test Conditions		Symbol	Min	Typ	Max	Unit
Operating Input Voltage			V_{IN}	1.7		5.5	V
Output Voltage Accuracy	$-40^{\circ}\text{C} \leq T_J \leq 85^{\circ}\text{C}$	$V_{OUT} \leq 2.0\text{ V}$	V_{OUT}	-40		+40	mV
		$V_{OUT} > 2.0\text{ V}$		-2		+2	%
Line Regulation	$V_{OUT} + 0.5\text{ V} \leq V_{IN} \leq 5.5\text{ V}$ ($V_{IN} \geq 1.7\text{ V}$)		Reg_{LINE}		0.01	0.1	%/V
Load Regulation – XDFN4 package	$I_{OUT} = 1\text{ mA}$ to 300 mA		Reg_{LOAD}		12	30	mV
Load Regulation – TSOP-5 package					28	45	
Dropout Voltage – XDFN4 package (Note 5)	$I_{OUT} = 300\text{ mA}$	$V_{OUT} = 1.8\text{ V}$	V_{DO}		425	560	mV
		$V_{OUT} = 2.8\text{ V}$			250	320	
		$V_{OUT} = 3.3\text{ V}$			215	260	
Dropout Voltage – TSOP-5 package (Note 5)	$I_{OUT} = 300\text{ mA}$	$V_{OUT} = 1.8\text{ V}$	V_{DO}		445	580	mV
		$V_{OUT} = 2.8\text{ V}$			270	340	
		$V_{OUT} = 3.3\text{ V}$			235	280	
Output Current Limit	$V_{OUT} = 90\% V_{OUT(nom)}$		I_{CL}	300	600		mA
Quiescent Current	$I_{OUT} = 0\text{ mA}$		I_Q		50	95	μA
Shutdown Current	$V_{EN} \leq 0.4\text{ V}$, $V_{IN} = 5.5\text{ V}$		I_{DIS}		0.01	1	μA
EN Pin Threshold Voltage High Threshold Low Threshold	V_{EN} Voltage increasing V_{EN} Voltage decreasing		V_{EN_HI} V_{EN_LO}	0.9		0.4	V
V_{OUT} Slew Rate (Note 6)	$V_{OUT} = 3.3\text{ V}$, $I_{OUT} = 10\text{ mA}$	Normal (version A and B)	V_{OUT_SR}		190		mV/ μs
		Slow (version C and D)			20		
EN Pin Input Current	$V_{EN} = 5.5\text{ V}$		I_{EN}		0.3	1.0	μA
Power Supply Rejection Ratio	$V_{IN} = 3.8\text{ V}$, $V_{OUT} = 3.5\text{ V}$ $I_{OUT} = 10\text{ mA}$	$f = 1\text{ kHz}$	PSRR		70		dB
Output Noise Voltage	$f = 10\text{ Hz}$ to 100 kHz		V_N		70		μV_{rms}
Thermal Shutdown Temperature	Temperature increasing from $T_J = +25^{\circ}\text{C}$		T_{SD}		160		$^{\circ}\text{C}$
Thermal Shutdown Hysteresis	Temperature falling from T_{SD}		T_{SDH}		20		$^{\circ}\text{C}$
Active Output Discharge Resistance	$V_{EN} < 0.4\text{ V}$, Version A and C only		R_{DIS}		100		Ω

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

4. Performance guaranteed over the indicated operating temperature range by design and/or characterization. Production tested at $T_J = T_A = 25^{\circ}\text{C}$. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.
5. Characterized when V_{OUT} falls 100 mV below the regulated voltage at $V_{IN} = V_{OUT(NOM)} + 1\text{ V}$.
6. Please refer OPN to determine slew rate. NCP115A, NCP115B – Normal speed. NCP115C, NCP115D – slower speed

TYPICAL CHARACTERISTICS

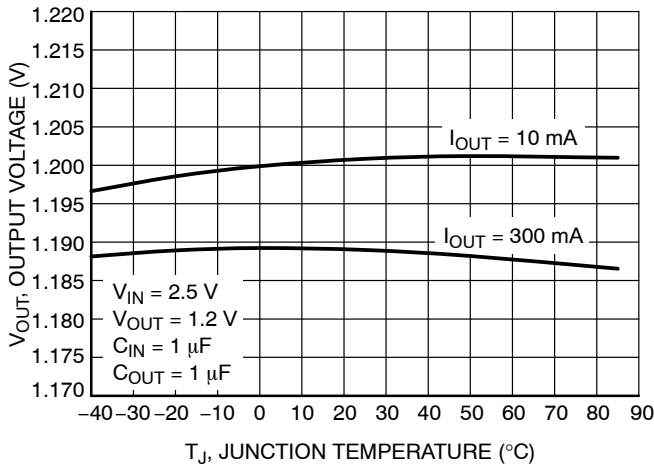


Figure 3. Output Voltage vs. Temperature – $V_{OUT} = 1.2\text{ V}$ – XDFN4

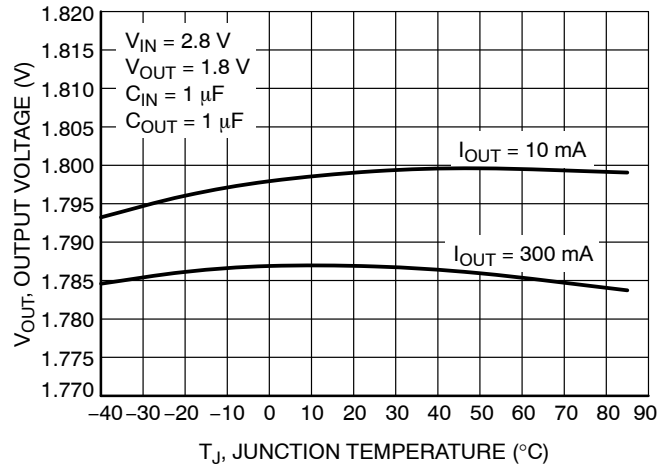


Figure 4. Output Voltage vs. Temperature – $V_{OUT} = 1.8\text{ V}$ – XDFN4

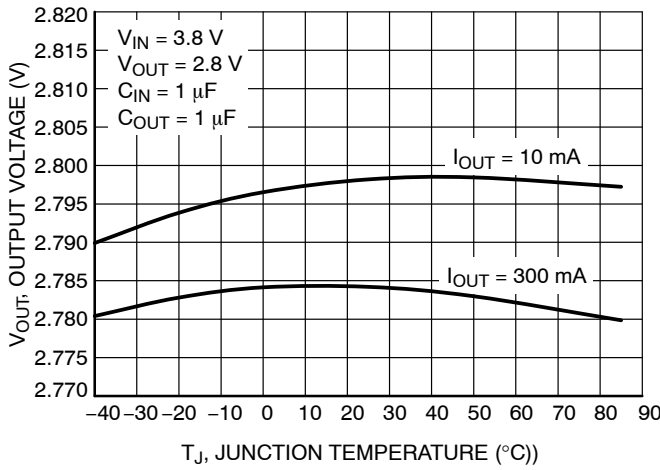


Figure 5. Output Voltage vs. Temperature – $V_{OUT} = 2.8\text{ V}$ – XDFN4

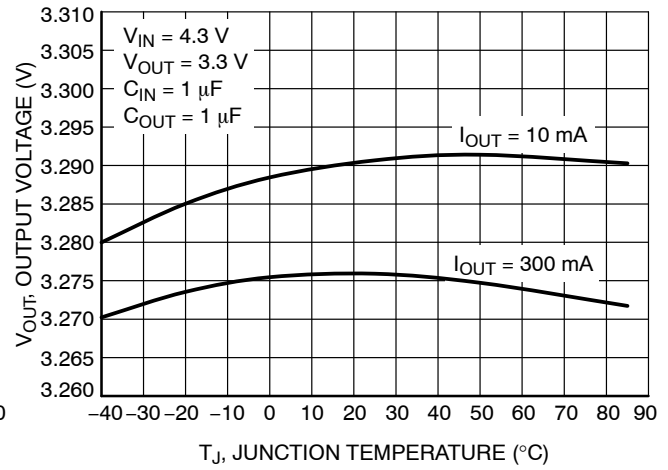


Figure 6. Output Voltage vs. Temperature – $V_{OUT} = 3.3\text{ V}$ – XDFN4

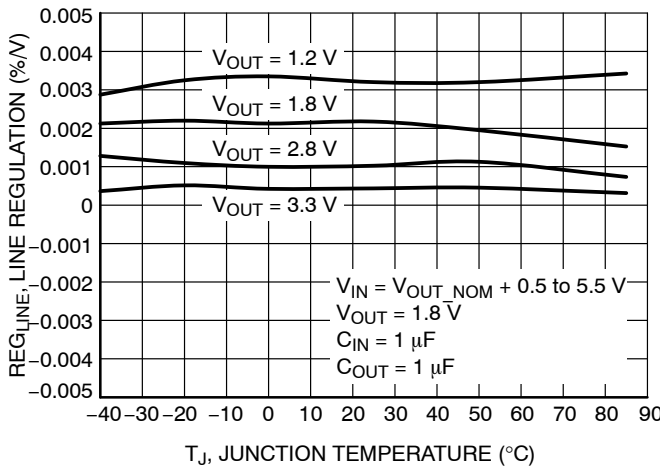


Figure 7. Line Regulation vs. Temperature

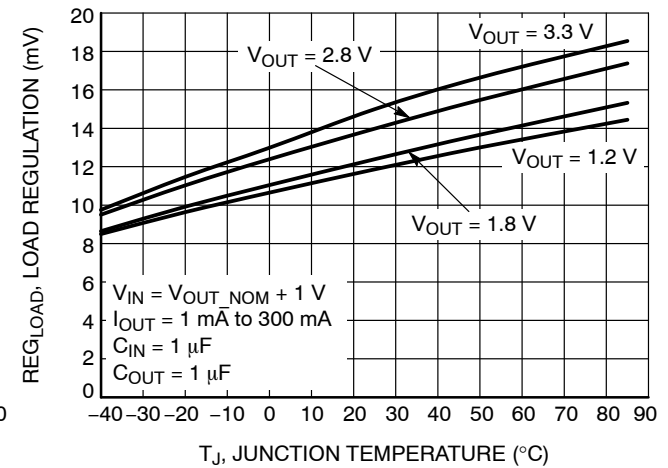


Figure 8. Load Regulation vs. Temperature – XDFN4

TYPICAL CHARACTERISTICS

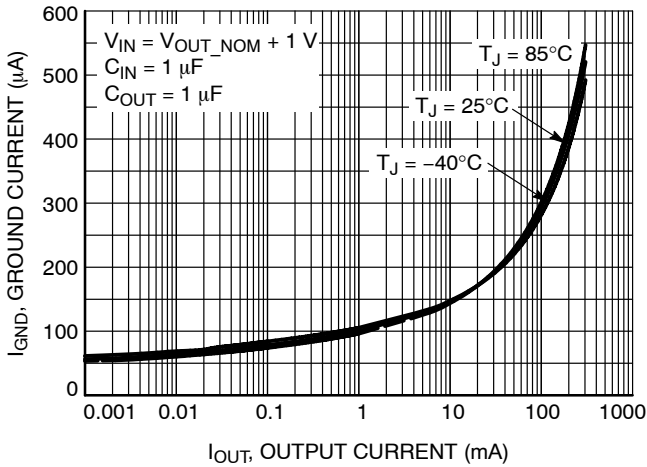


Figure 9. Ground Current vs. Load Current

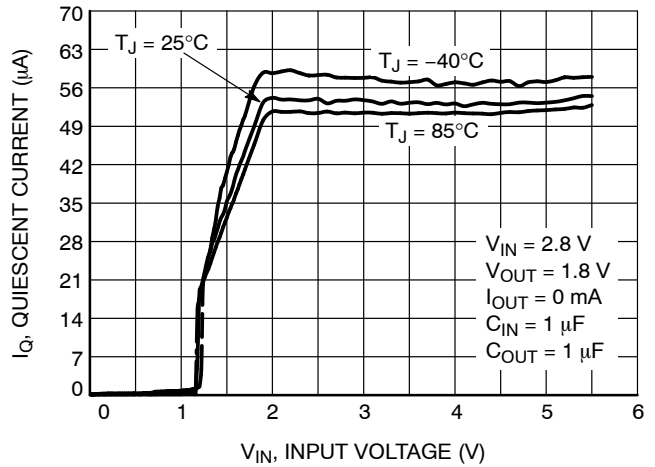


Figure 10. Quiescent Current vs. Input Voltage
V_{OUT} = 1.8 V

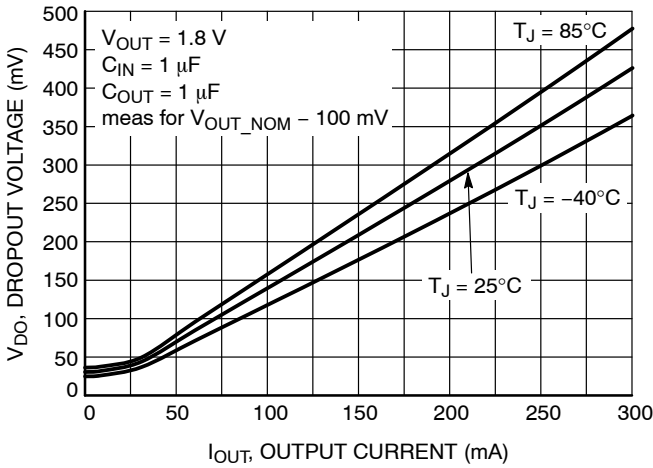


Figure 11. Dropout Voltage vs. Load Current -
V_{OUT} = 1.8 V

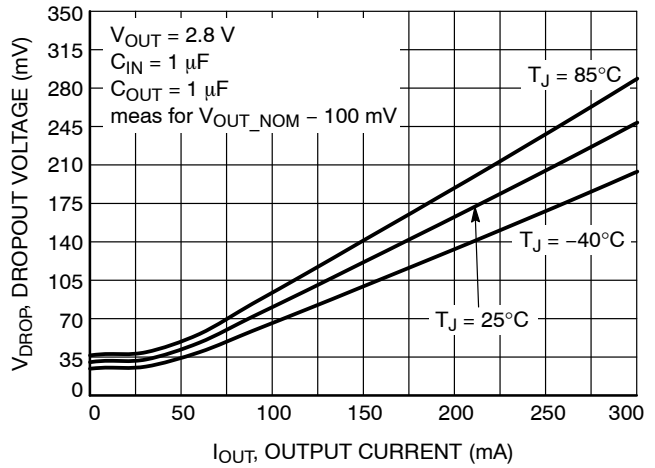


Figure 12. Dropout Voltage vs. Load Current -
V_{OUT} = 2.8 V

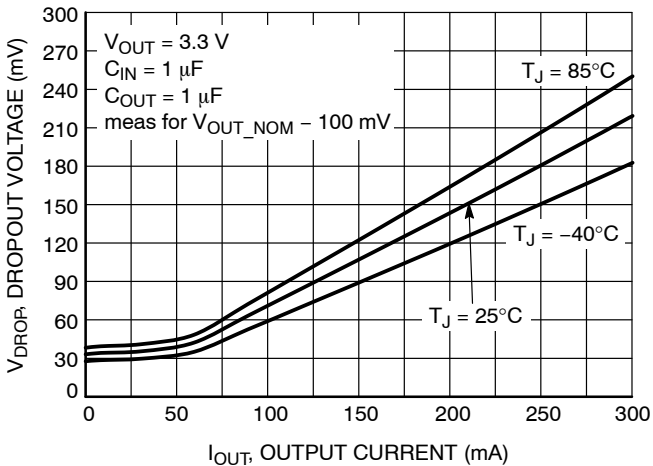


Figure 13. Dropout Voltage vs. Load Current -
V_{OUT} = 3.3 V

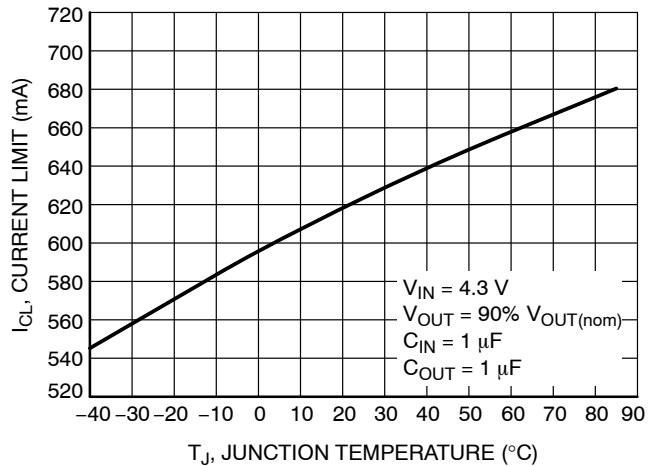


Figure 14. Current Limit vs. Temperature

TYPICAL CHARACTERISTICS

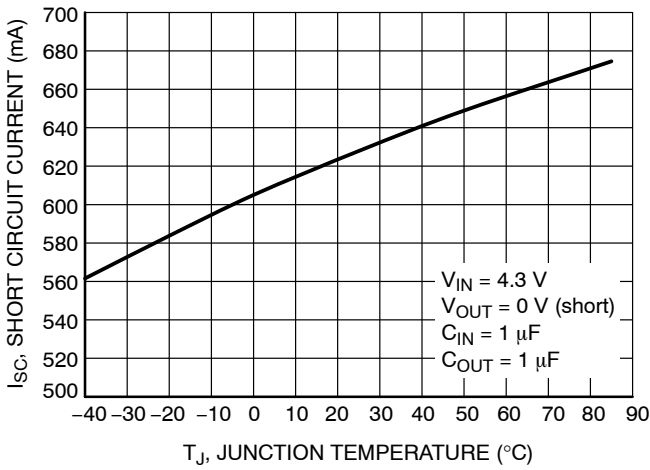


Figure 15. Short Circuit Current vs. Temperature

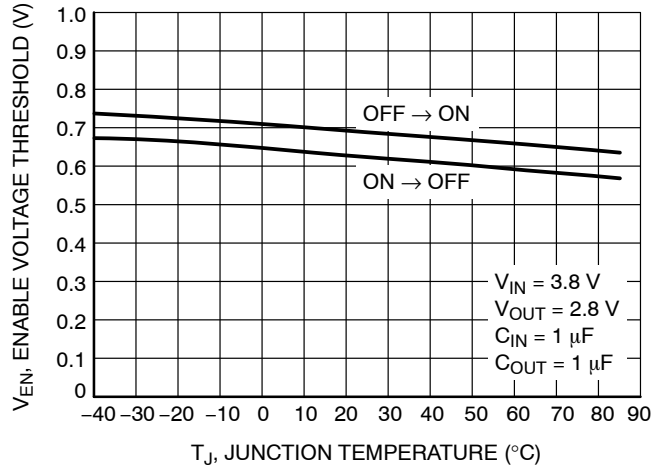


Figure 16. Enable Thresholds Voltage

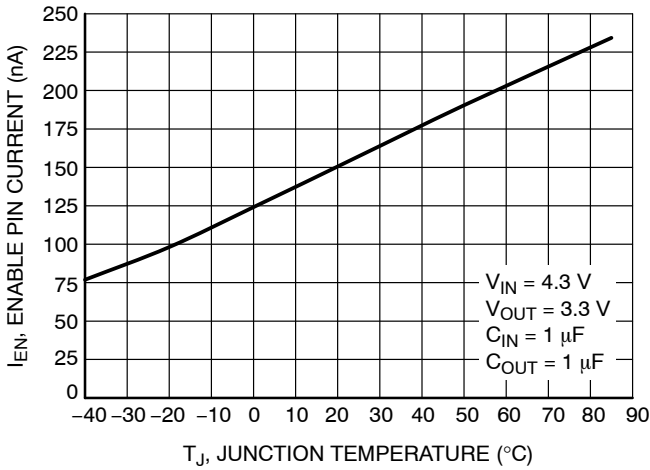


Figure 17. Current to Enable Pin vs. Temperature

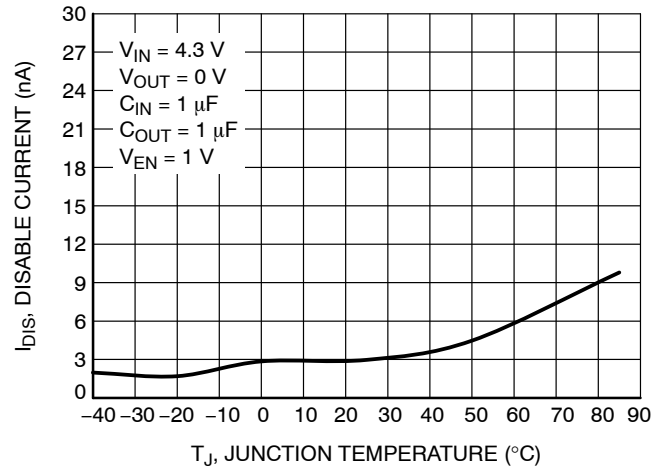


Figure 18. Disable Current vs. Temperature

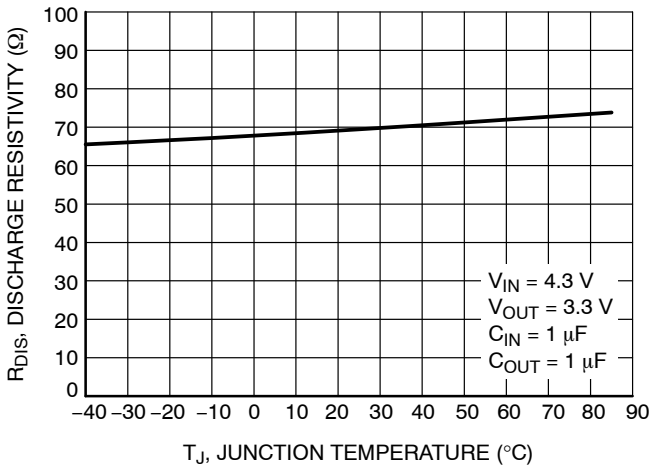


Figure 19. Discharge Resistance vs. Temperature

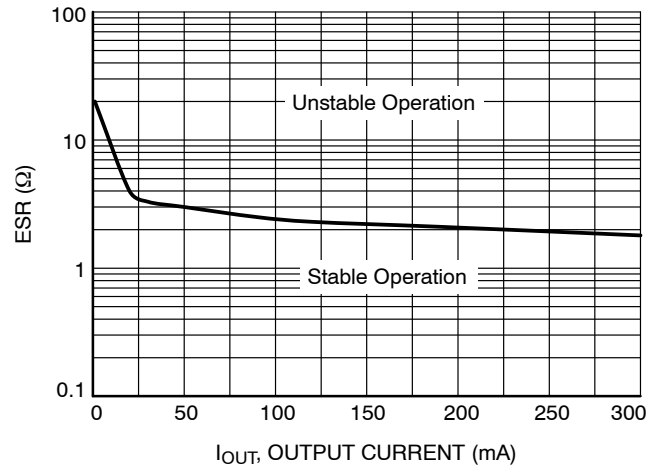
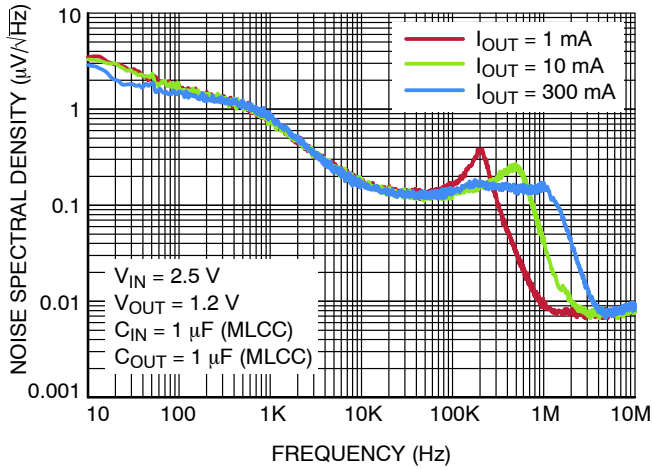


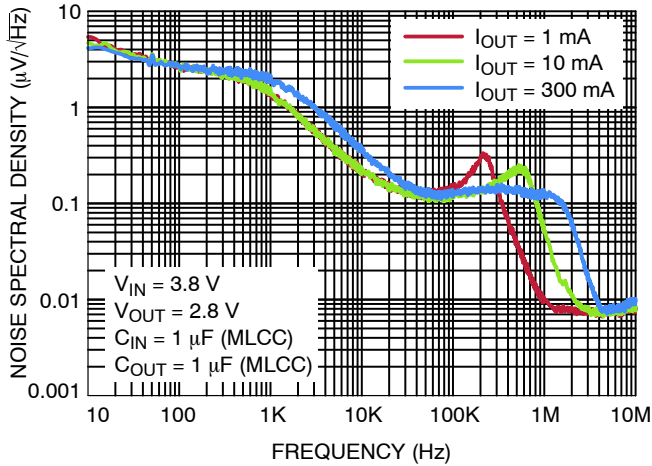
Figure 20. Maximum C_{OUT} ESR Value vs. Load Current

TYPICAL CHARACTERISTICS



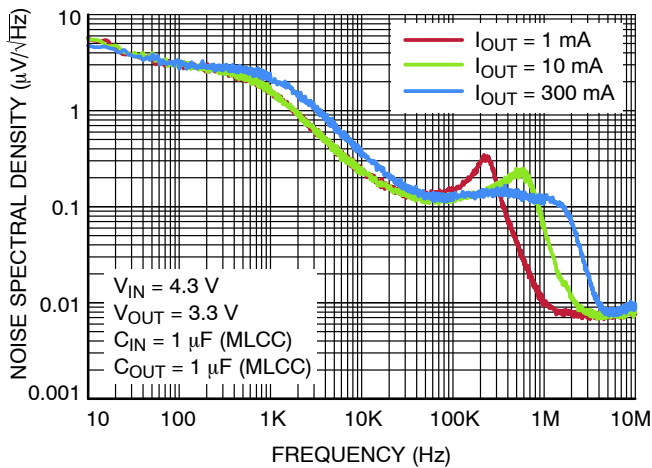
I_{OUT}	RMS Output Noise (μV_{RMS})	
	10 Hz – 100 kHz	100 Hz – 100 kHz
1 mA	65.6	61.9
10 mA	63.1	59.5
300 mA	62.3	60.3

Figure 21. Output Voltage Noise Spectral Density – $V_{OUT} = 1.2\text{ V}$



I_{OUT}	RMS Output Noise (μV_{RMS})	
	10 Hz – 100 kHz	100 Hz – 100 kHz
1 mA	93.4	87.9
10 mA	92.1	86.6
300 mA	119.3	115.6

Figure 22. Output Voltage Noise Spectral Density – $V_{OUT} = 2.8\text{ V}$



I_{OUT}	RMS Output Noise (μV_{RMS})	
	10 Hz – 100 kHz	100 Hz – 100 kHz
1 mA	104.0	98.0
10 mA	102.9	96.7
300 mA	131.4	127.0

Figure 23. Output Voltage Noise Spectral Density – $V_{OUT} = 3.3\text{ V}$

TYPICAL CHARACTERISTICS

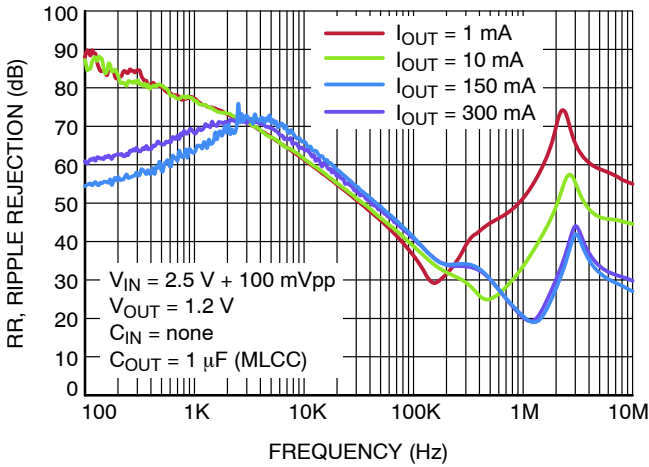


Figure 24. Power Supply Rejection Ratio, $V_{OUT} = 1.2\text{ V}$

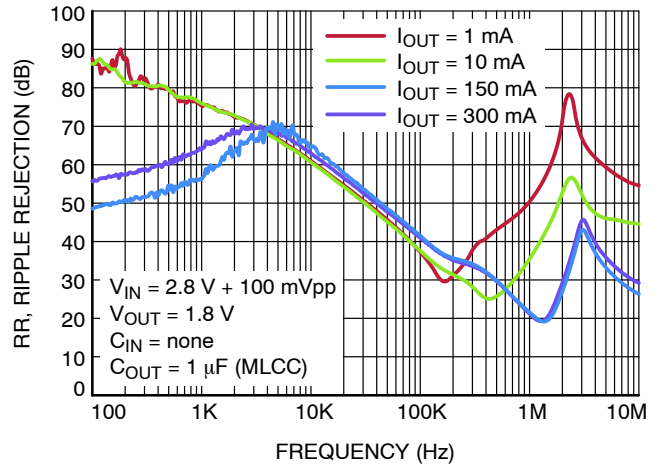


Figure 25. Power Supply Rejection Ratio, $V_{OUT} = 1.8\text{ V}$

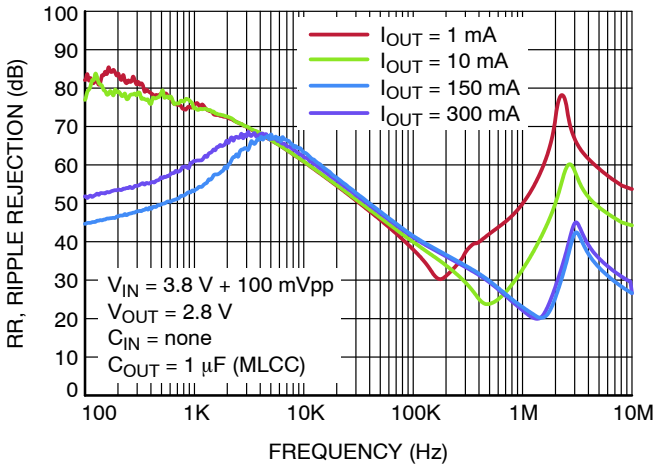


Figure 26. Power Supply Rejection Ratio, $V_{OUT} = 2.8\text{ V}$

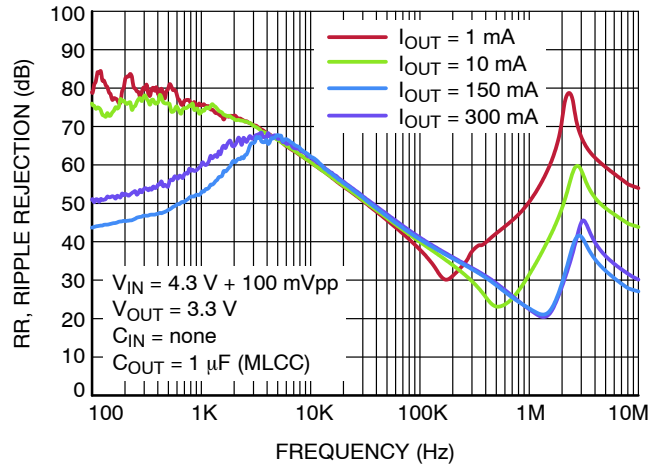


Figure 27. Power Supply Rejection Ratio, $V_{OUT} = 3.3\text{ V}$

TYPICAL CHARACTERISTICS

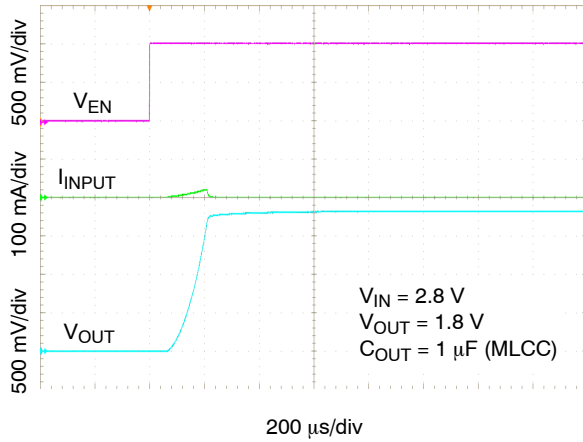


Figure 28. Enable Turn-on Response – $I_{OUT} = 0$ mA, Slow Option – C

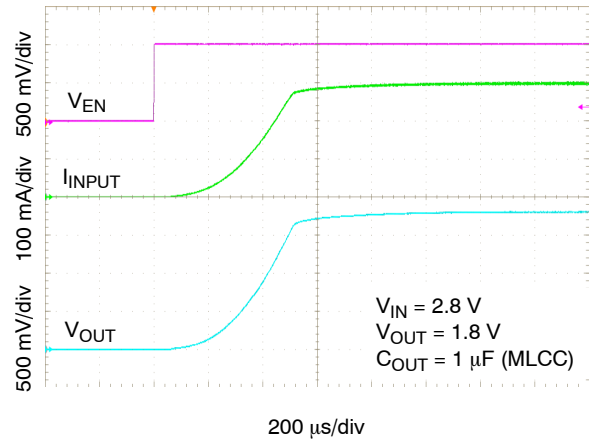


Figure 29. Enable Turn-on Response – $I_{OUT} = 300$ mA, Slow Option – C

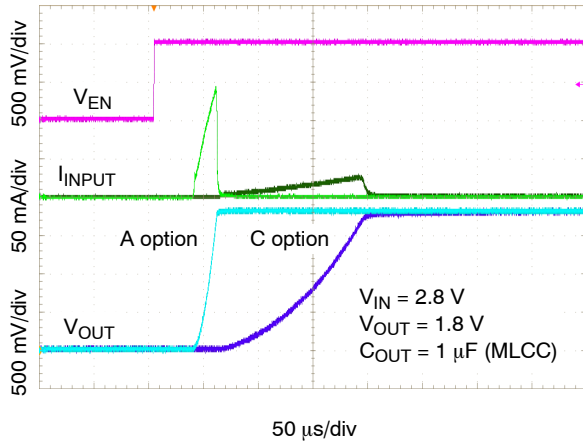


Figure 30. V_{OUT} Slew-Rate Comparison A and C option – $I_{OUT} = 10$ mA

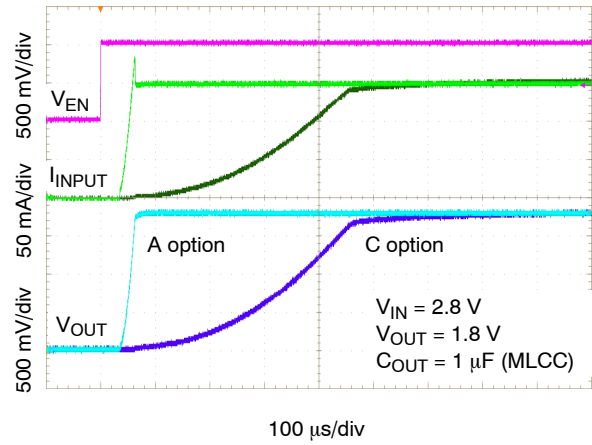


Figure 31. V_{OUT} Slew-Rate Comparison A and C option – $I_{OUT} = 300$ mA

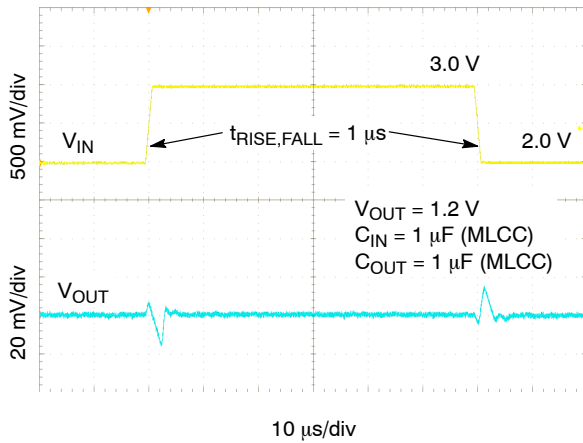


Figure 32. Line Transient Response – $I_{OUT} = 10$ mA

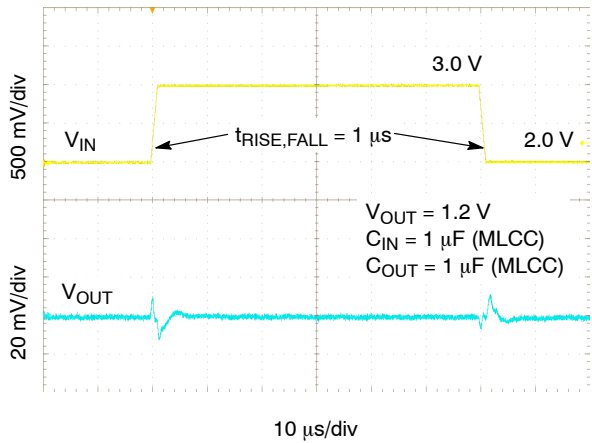


Figure 33. Line Transient Response – $I_{OUT} = 300$ mA

TYPICAL CHARACTERISTICS

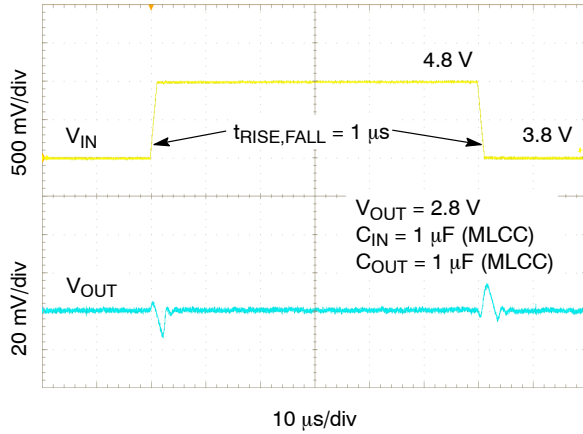


Figure 34. Line Transient Response - $I_{OUT} = 10 \text{ mA}$

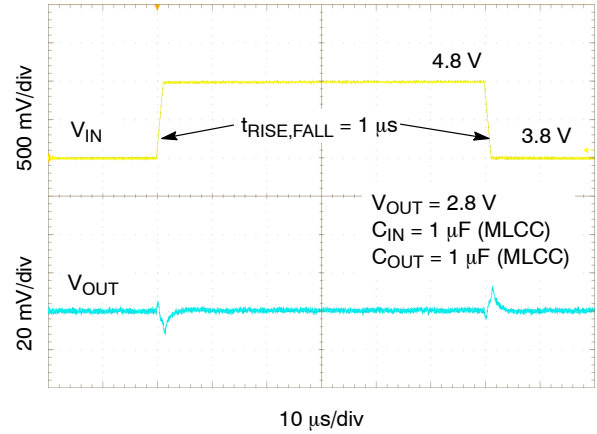


Figure 35. Line Transient Response - $I_{OUT} = 300 \text{ mA}$

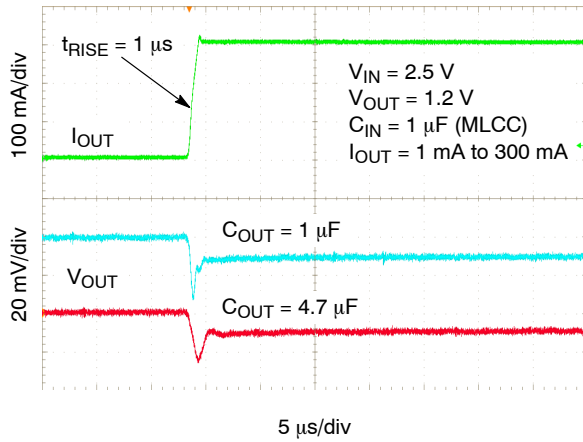


Figure 36. Load Transient Response - $V_{OUT} = 1.2 \text{ V}$

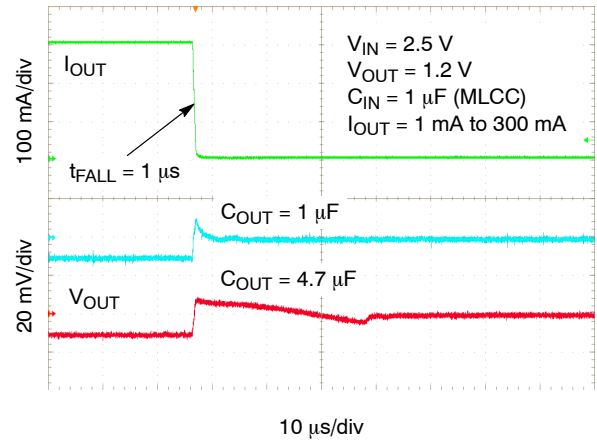


Figure 37. Load Transient Response - $V_{OUT} = 1.2 \text{ V}$

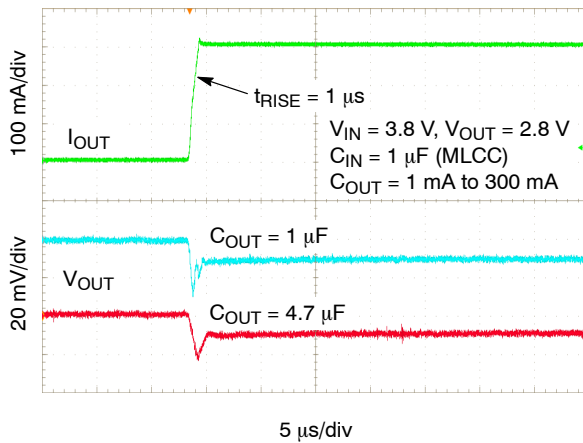


Figure 38. Load Transient Response - $V_{OUT} = 2.8 \text{ V}$

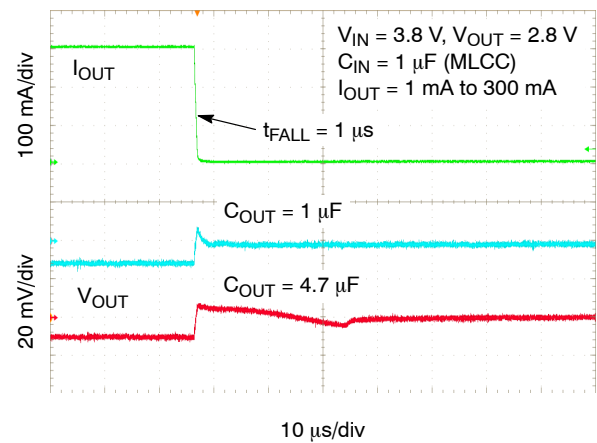


Figure 39. Load Transient Response - $V_{OUT} = 2.8 \text{ V}$

TYPICAL CHARACTERISTICS

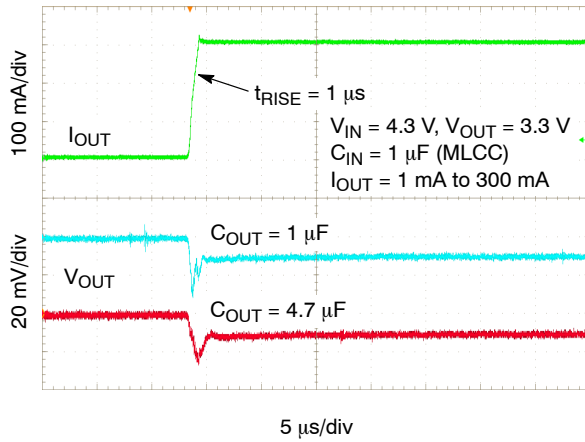


Figure 40. Load Transient Response - $V_{OUT} = 3.3\text{ V}$

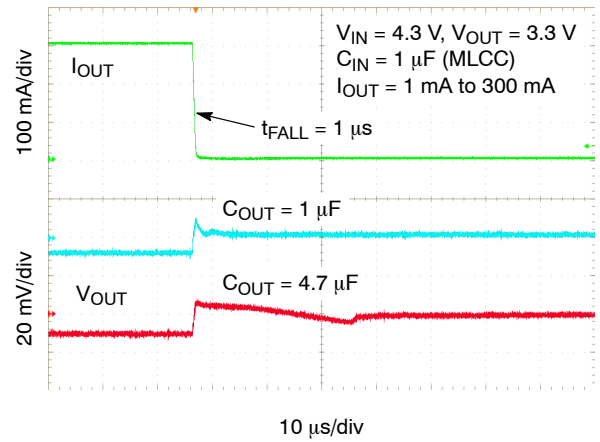


Figure 41. Load Transient Response - $V_{OUT} = 3.3\text{ V}$

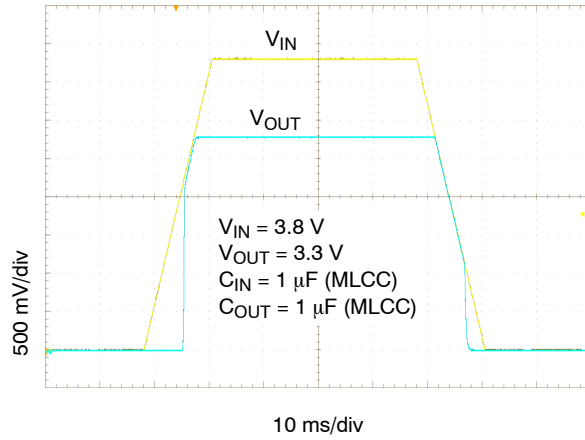


Figure 42. Turn-on/off - Slow Rising $V_{IN} - I_{OUT} = 10\text{ mA}$

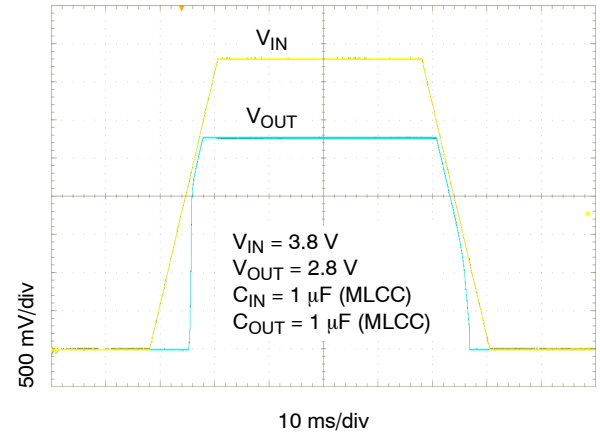


Figure 43. Turn-on/off - Slow Rising $V_{IN} - I_{OUT} = 300\text{ mA}$

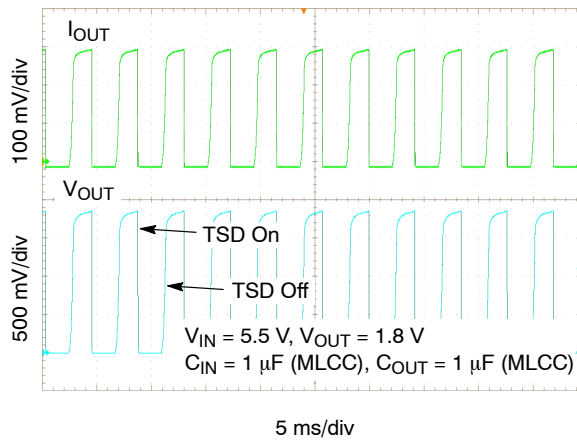


Figure 44. Overheating Protection - TSD

APPLICATIONS INFORMATION

General

The NCP115 is a high performance 300 mA Low Dropout Linear Regulator. This device delivers very high PSRR (over 70 dB at 1 kHz) and excellent dynamic performance as load/line transients. In connection with very low quiescent current this device is very suitable for various battery powered applications such as tablets, cellular phones, wireless and many others. The device is fully protected in case of output overload, output short circuit condition and overheating, assuring a very robust design.

Input Capacitor Selection (C_{IN})

It is recommended to connect at least a 1 µF Ceramic X5R or X7R capacitor as close as possible to the IN pin of the device. This capacitor will provide a low impedance path for unwanted AC signals or noise modulated onto constant input voltage. There is no requirement for the min. /max. ESR of the input capacitor but it is recommended to use ceramic capacitors for their low ESR and ESL. A good input capacitor will limit the influence of input trace inductance and source resistance during sudden load current changes. Larger input capacitor may be necessary if fast and large load transients are encountered in the application.

Output Decoupling (C_{OUT})

The NCP115 requires an output capacitor connected as close as possible to the output pin of the regulator. The recommended capacitor value is 1 µF and X7R or X5R dielectric due to its low capacitance variations over the specified temperature range. The NCP115 is designed to remain stable with minimum effective capacitance of 0.47 µF to account for changes with temperature, DC bias and package size. Especially for small package size capacitors such as 0402 the effective capacitance drops rapidly with the applied DC bias.

There is no requirement for the minimum value of Equivalent Series Resistance (ESR) for the C_{OUT} but the maximum value of ESR should be less than 1.8 Ω. Larger output capacitors and lower ESR could improve the load transient response or high frequency PSRR. It is not recommended to use tantalum capacitors on the output due to their large ESR. The equivalent series resistance of tantalum capacitors is also strongly dependent on the temperature, increasing at low temperature.

Enable Operation

The NCP115 uses the EN pin to enable/disable its device and to deactivate/activate the active discharge function.

If the EN pin voltage is <0.4 V the device is guaranteed to be disabled. The pass transistor is turned-off so that there is virtually no current flow between the IN and OUT. The active discharge transistor is active so that the output voltage V_{OUT} is pulled to GND through a 100 Ω resistor. In the

disable state the device consumes as low as typ. 10 nA from the V_{IN}.

If the EN pin voltage >0.9 V the device is guaranteed to be enabled. The NCP115 regulates the output voltage and the active discharge transistor is turned-off.

The EN pin has internal pull-down current source with typ. value of 300 nA which assures that the device is turned-off when the EN pin is not connected. In the case where the EN function isn't required the EN should be tied directly to IN.

Output Current Limit

Output Current is internally limited within the IC to a typical 600 mA. The NCP115 will source this amount of current measured with a voltage drops on the 90% of the nominal V_{OUT}. If the Output Voltage is directly shorted to ground (V_{OUT} = 0 V), the short circuit protection will limit the output current to 630 mA (typ). The current limit and short circuit protection will work properly over whole temperature range and also input voltage range. There is no limitation for the short circuit duration.

Thermal Shutdown

When the die temperature exceeds the Thermal Shutdown threshold (T_{SD} – 160°C typical), Thermal Shutdown event is detected and the device is disabled. The IC will remain in this state until the die temperature decreases below the Thermal Shutdown Reset threshold (T_{SDU} – 140°C typical). Once the IC temperature falls below the 140°C the LDO is enabled again. The thermal shutdown feature provides the protection from a catastrophic device failure due to accidental overheating. This protection is not intended to be used as a substitute for proper heat sinking.

Power Dissipation

As power dissipated in the NCP115 increases, it might become necessary to provide some thermal relief. The maximum power dissipation supported by the device is dependent upon board design and layout. Mounting pad configuration on the PCB, the board material, and the ambient temperature affect the rate of junction temperature rise for the part.

The maximum power dissipation the NCP115 can handle is given by:

$$P_{D(MAX)} = \frac{[85^{\circ}C - T_A]}{\theta_{JA}} \quad (\text{eq. 1})$$

The power dissipated by the NCP115 for given application conditions can be calculated from the following equations:

$$P_D \approx V_{IN}(I_{GND@I_{OUT}}) + I_{OUT}(V_{IN} - V_{OUT}) \quad (\text{eq. 2})$$

NCP115

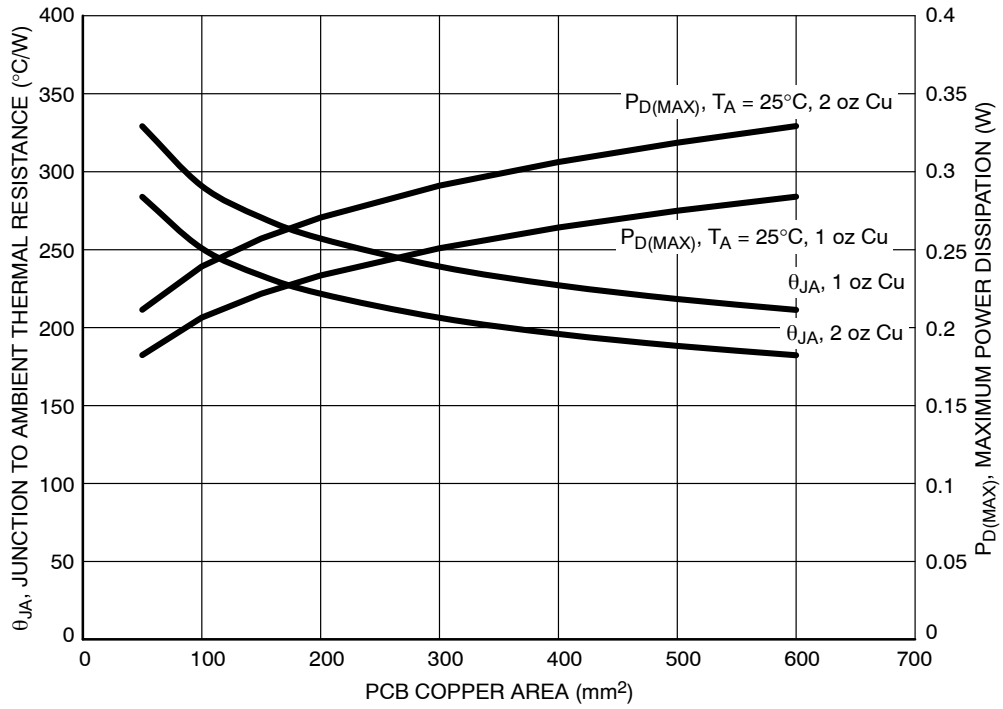


Figure 45. θ_{JA} and $P_{D(MAX)}$ vs. Copper Area (XDFN4)

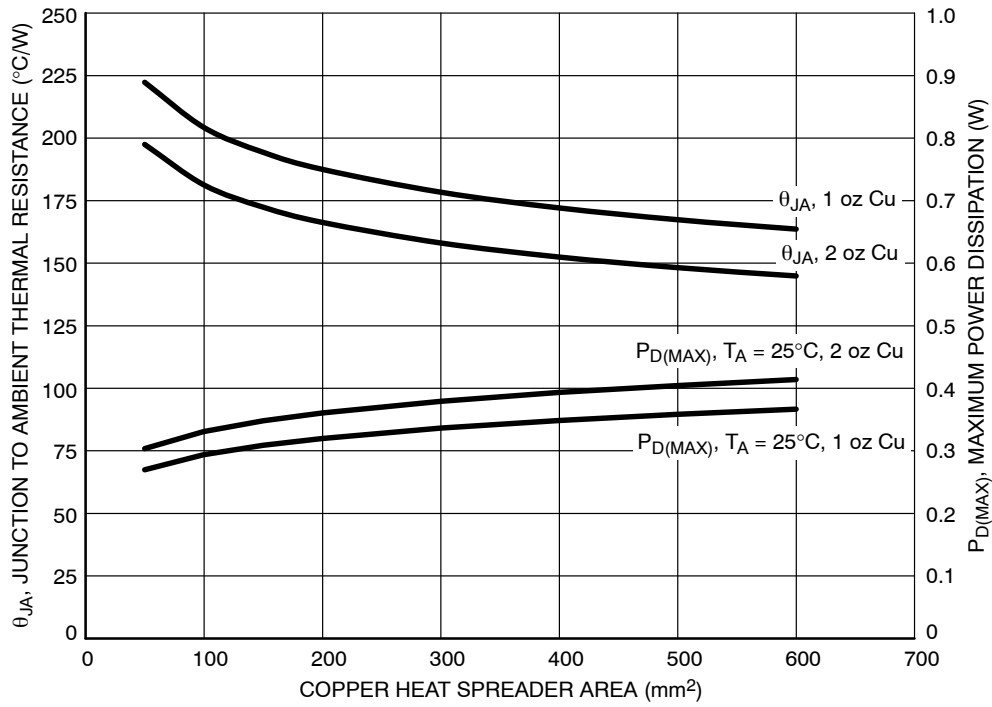


Figure 46. θ_{JA} and $P_{D(MAX)}$ vs. Copper Area (TSOP-5)

NCP115

Reverse Current

The PMOS pass transistor has an inherent body diode which will be forward biased in the case that $V_{OUT} > V_{IN}$. Due to this fact in cases, where the extended reverse current condition can be anticipated the device may require additional external protection.

Power Supply Rejection Ratio

The NCP115 features very good Power Supply Rejection ratio. If desired the PSRR at higher frequencies in the range 100 kHz – 10 MHz can be tuned by the selection of C_{OUT} capacitor and proper PCB layout.

Turn-On Time

The turn-on time is defined as the time period from EN assertion to the point in which V_{OUT} will reach 98% of its nominal value. This time is dependent on various application conditions such as $V_{OUT(NOM)}$, C_{OUT} and T_A .

The NCP115 provides two options of V_{OUT} ramp-up time. The NCP115A and NCP115B have normal slew rate, typical 190 mV/ μ s and NCP115C and NCP115D provide slower option with typical value 20 mV/ μ s which is suitable for camera sensor and other sensitive devices.

PCB Layout Recommendations

To obtain good transient performance and good regulation characteristics place C_{IN} and C_{OUT} capacitors close to the device pins and make the PCB traces wide. In order to minimize the solution size, use 0402 capacitors. Larger copper area connected to the pins will also improve the device thermal resistance. The actual power dissipation can be calculated from the equation above (Equation 2). Expose pad should be tied the shortest path to the GND pin.

NCP115

ORDERING INFORMATION – XDFN4 PACKAGE

Device	Voltage Option	Marking	Description	Package	Shipping
NCP115AMX100TCG	1.0 V	QN	300 mA, Active Discharge, Normal Slew-rate	XDFN4 (Pb-Free)	3000 / Tape & Reel
NCP115AMX105TCG	1.05 V	QM			
NCP115AMX110TBG	1.1 V	QL			
NCP115AMX110TCG					
NCP115AMX120TBG	1.2 V	QA			
NCP115AMX120TCG					
NCP115AMX150TCG	1.5 V	QE			
NCP115AMX180TBG	1.8 V	QC			
NCP115AMX180TCG					
NCP115AMX250TCG	2.5 V	QF			
NCP115AMX280TBG	2.8 V	QG			
NCP115AMX280TCG					
NCP115AMX300TCG	3.0 V	QK			
NCP115AMX330TBG	3.3 V	QH			
NCP115AMX330TCG					
NCP115AMX360TCG	3.6 V	QJ			
NCP115CMX100TCG	1.0 V	RN	300 mA, Active Discharge, Slow Slew-rate		
NCP115CMX105TCG	1.05 V	RM			
NCP115CMX110TBG	1.1 V	RF			
NCP115CMX110TCG					
NCP115CMX120TBG	1.2 V	RE			
NCP115CMX120TCG					
NCP115CMX150TCG	1.5 V	RG			
NCP115CMX180TBG	1.8 V	RA			
NCP115CMX180TCG					
NCP115CMX250TCG	2.5 V	RH			
NCP115CMX280TBG	2.8 V	RC			
NCP115CMX280TCG					
NCP115CMX300TCG	3.0 V	RK			
NCP115CMX330TBG	3.3 V	RD			
NCP115CMX330TCG					
NCP115CMX360TCG	3.6 V	RJ			

NCP115

ORDERING INFORMATION – TSOP–5 PACKAGE

Device	Voltage Option	Marking	Description	Package	Shipping
NCP115ASN105T1G	1.05 V	QAC	300 mA, Active Discharge, Normal Slew–rate	TSOP–5 (Pb–Free)	3000 / Tape & Reel
NCP115ASN110T1G	1.1 V	QAD			
NCP115ASN120T1G	1.2 V	QAE			
NCP115ASN120T2G	1.2 V	QAE			
NCP115ASN150T1G	1.5 V	QAF			
NCP115ASN150T2G	1.5 V	QAF			
NCP115ASN180T1G	1.8 V	QAA			
NCP115ASN180T2G	1.8 V	QAA			
NCP115ASN250T1G	2.5 V	QAG			
NCP115ASN250T2G	2.5 V	QAG			
NCP115ASN280T1G	2.8 V	QAH			
NCP115ASN280T2G	2.8 V	QAH			
NCP115ASN300T1G	3.0 V	QAJ			
NCP115ASN330T1G	3.3 V	QAK			
NCP115ASN330T2G	3.3 V	QAK			
NCP115CSN105T1G	1.05 V	QCC	300 mA, Active Discharge, Slow Slew–rate	TSOP–5 (Pb–Free)	3000 / Tape & Reel
NCP115CSN110T1G	1.1 V	QCD			
NCP115CSN120T1G	1.2 V	QCE			
NCP115CSN150T1G	1.5 V	QCF			
NCP115CSN180T1G	1.8 V	QCA			
NCP115CSN250T1G	2.5 V	QCG			
NCP115CSN280T1G	2.8 V	QCH			
NCP115CSN300T1G	3.0 V	QCJ			
NCP115CSN330T1G	3.3 V	QCK			

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MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

ON Semiconductor®



SCALE 2:1

TSOP-5 CASE 483 ISSUE N

DATE 12 AUG 2020



NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE. DIMENSION A.
5. OPTIONAL CONSTRUCTION: AN ADDITIONAL TRIMMED LEAD IS ALLOWED IN THIS LOCATION. TRIMMED LEAD NOT TO EXTEND MORE THAN 0.2 FROM BODY.

DIM	MILLIMETERS	
	MIN	MAX
A	2.85	3.15
B	1.35	1.65
C	0.90	1.10
D	0.25	0.50
G	0.95 BSC	
H	0.01	0.10
J	0.10	0.26
K	0.20	0.60
M	0°	10°
S	2.50	3.00

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



- XXX = Specific Device Code
- A = Assembly Location
- Y = Year
- W = Work Week
- XXX = Specific Device Code
- M = Date Code
- = Pb-Free Package
- = Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present.

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MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

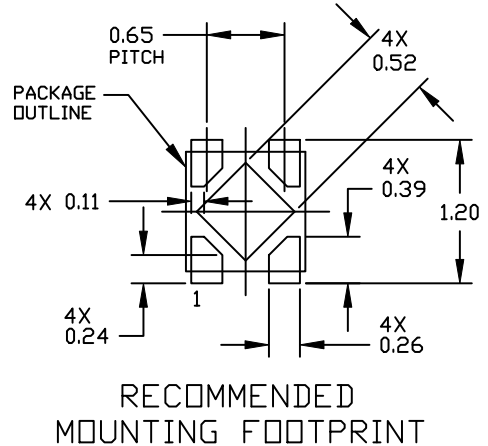
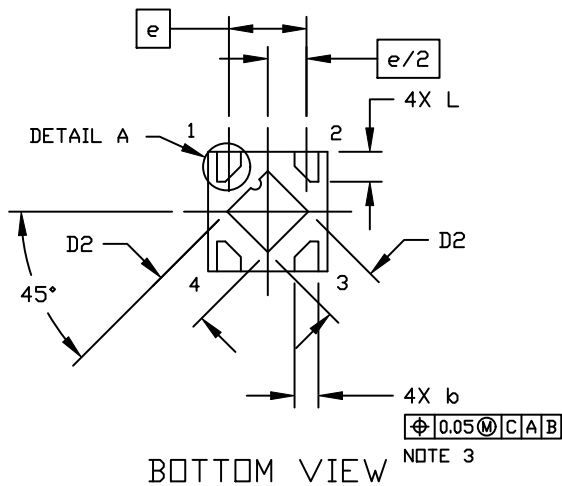
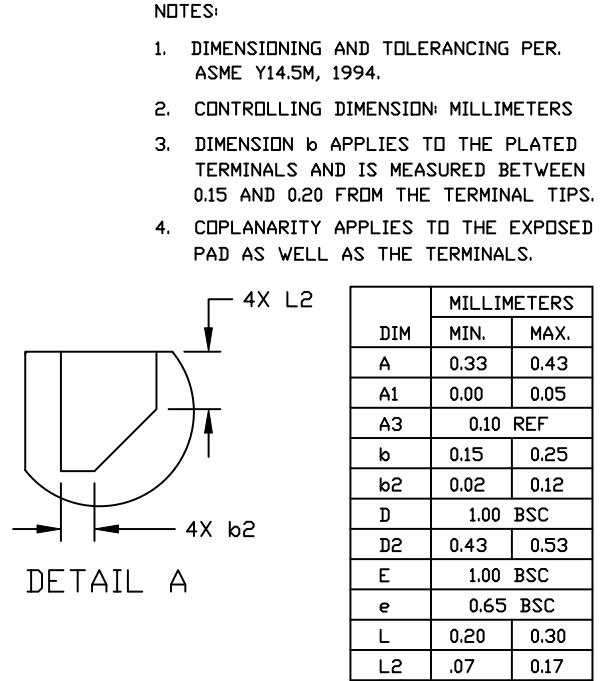
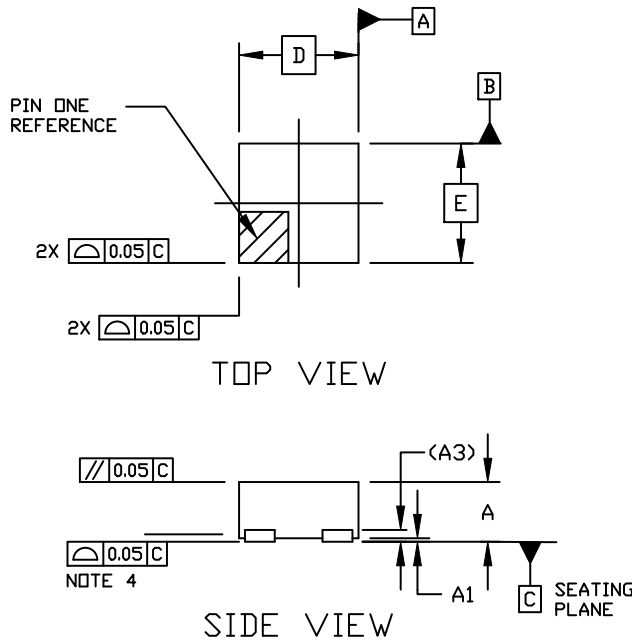
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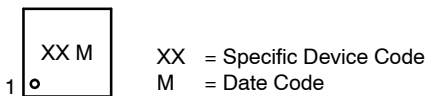
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XDFN4 1.0x1.0, 0.65P
CASE 711AJ
ISSUE B

DATE 25 JUN 2021



GENERIC MARKING DIAGRAM*



*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "μ", may or may not be present. Some products may not follow the Generic Marking.

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